PNP/NPN Epitaxial Planar Silicon Transistors

[CPH6104/6204]



CPH6104/CPH6204

1 : Collector

2 : Collector 3 : Base 4 : Emitter 5 : Collector

6 : Collector

SANYO : CPH6

High-Current Switching Applications

Package Dimensions

unit:mm

2146A

Applications

• DC-DC converter, relay drivers, lamp drivers, motor drivers, strobes.

Features

- · Adoption of FBET, MBIT processes.
- · High current capacitance.
- · Low collector-to-emitter saturation voltage.
- · High-speed switching.
- · Ultrasmall package permitting applied sets to be made small and slim (0.9mm).
- · High allowable power dissipation.

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Specifications

Absolute Maximum Ratings at $Ta = 25^{\circ}C$

Parameter		Symbol Conditions	Ratings	Unit
Collector-to-Base Voltage		V _{CBO}	(–)15	V
Collector-to-Emitter Voltage		VCEO	(–)15	V
Emitter-to-Base Voltage		VEBO	(–)5	V
Collector Current		l l c	(–)1.5	А
Collector Current (Pulse)	5 ³²⁶	ICP	(-)3	Α
Base Current		B	(–)200	mA
Collector Dissipation	1997 - 3497 -	P _C Mounted on a ceramic board (600mm ² ×0.8mm)	1.3	W
Junction Temperature	and the second	JAN V //	150	°C
Storage Temperature	A	Tstg	-55 to +150	°C

Electrical Characteristics at Ta = 25 C

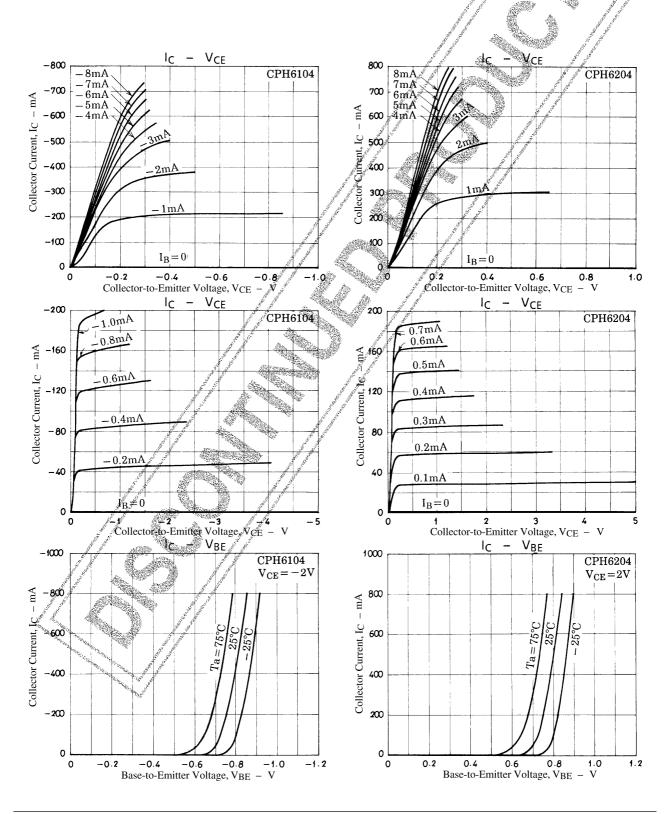
Parameter	Symbol	of the Conditions	Ratings			Unit	
Faiameter	ayinboi		min	typ	max	Unit	
Collector Cutoff Current	Ісво	V _{CB} =(–)12V, I _E =0			(–)100	nA	
Emitter Cutoff Current	IEBO	V _{EB} =(-)4V, I _C =0			(–)100	nA	
DC Current Gain	h/FB1	V _{CE} =(-)2V, I _C =(-)50mA	200		560		
1 1 mar Carrow March 19	h _{FE} 2	V _{CE} =(-)2V, I _C =(-)800mA	80				
Gain-Bandwidth Product	F	f _T V _{CE} =(-)2V, I _C =(-)50mA		(300)		MHz	
1 1 2 2 2 2 2 1	T'			200		MHz	
Output Capacitance	Cob	V _{CB} =(-)10V, f=1MHz		(15)10		pF	
Continued on next page							

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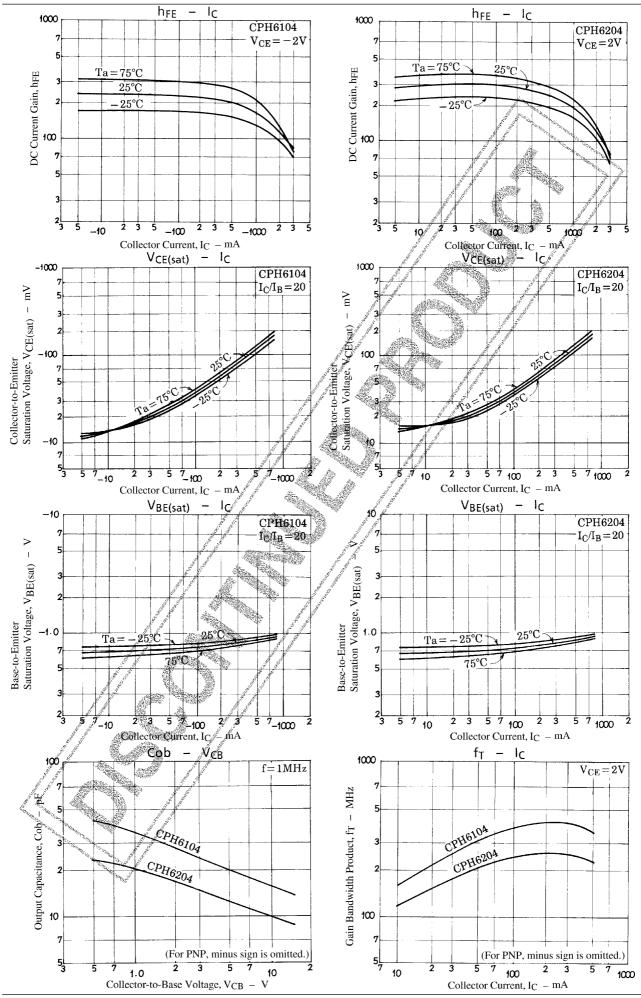
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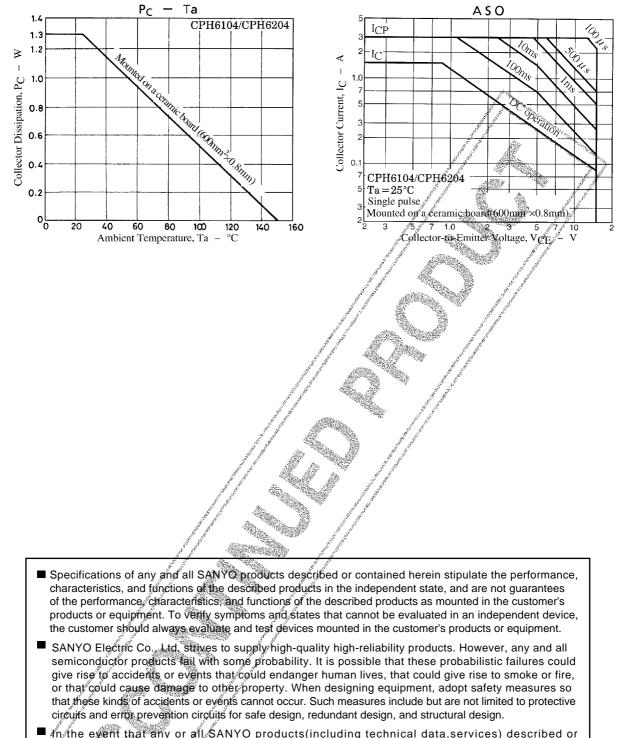
Parameter	Symbol	Conditions		Ratings		
Falameter	Symbol		min	typ	max	Unit
Collector-to-Emitter Saturation Voltage	V _{CE(sat)} 1	I _C =(-)5mA, I _B =(-)0.5mA		(–)10	(–)25	V
Collector-to-Emitter Saturation Voltage	V _{CE(sat)} 2	I _C =(–)500mA, I _B =(–)25mA	1 m	(–)120	(–)240	V
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =(-)500mA, I _B =(-)25mA	and a series	(_)0.9	(–)1.2	V
Collector-to-Base Breakdown Voltage	V _(BR) CBO	I _C =(-)10μA, I _E =0	()15	A State of the second second		V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C =(–)1mA, R _{BE} =∞	/ (–)15	and a second second	and a second	V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I _E =(-)10μΑ, I _C =0	(–)5		All House and a second	V



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